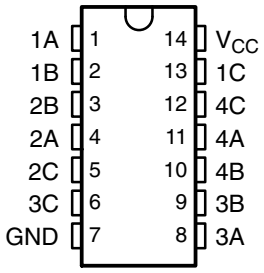
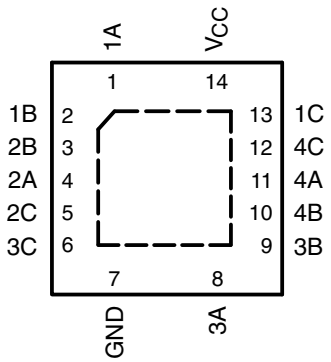
- **2-V to 5.5-V V_{CC} Operation**
- **Supports Mixed-Mode Voltage Operation on All Ports**
- **High On-Off Output-Voltage Ratio**
- **Low Crosstalk Between Switches**
- **Individual Switch Controls**
- **Extremely Low Input Current**
- **ESD Protection Exceeds JESD 22**
  - **2000-V Human-Body Model (A114-A)**
  - **200-V Machine Model (A115-A)**
  - **1000-V Charged-Device Model (C101)**

D, DB, DGV, N, NS, OR PW PACKAGE
(TOP VIEW)



RGY PACKAGE
(TOP VIEW)



NC – No internal connection

description/ordering information

This quadruple silicon-gate CMOS analog switch is designed for 2-V to 5.5-V V_{CC} operation.

This switch is designed to handle both analog and digital signals. Each switch permits signals with amplitudes up to 5.5 V (peak) to be transmitted in either direction.

Each switch section has its own enable-input control (C). A high-level voltage applied to C turns on the associated switch section.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

ORDERING INFORMATION

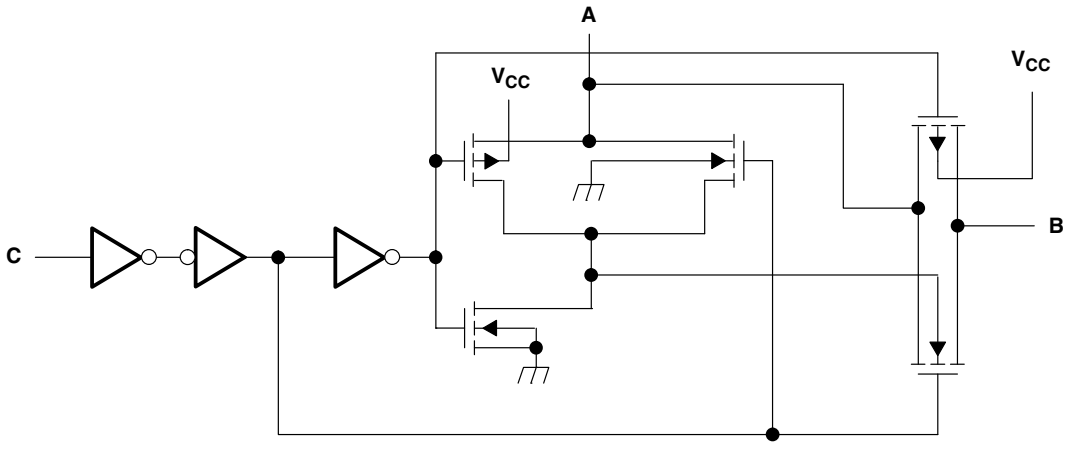
T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	PDIP – N	Tube	SN74AHC4066N	SN74AHC4066N
	QFN – RGY	Tape and reel	SN74AHC4066RGYR	HA4066
	SOIC – D	Tube	SN74AHC4066D	AHC4066
		Tape and reel	SN74AHC4066DR	
	SOP – NS	Tube	SN74AHC4066NS	AHC4066
		Tape and reel	SN74AHC4066NSR	
	SSOP – DB	Tube	SN74AHC4066DB	HA4066
		Tape and reel	SN74AHC4066DBR	
	TSSOP – PW	Tube	SN74AHC4066PW	HA4066
		Tape and reel	SN74AHC4066PWR	
	TVSOP – DGV	Tape and reel	SN74AHC4066DGVR	HA4066

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE
(each switch)

INPUT CONTROL (C)	SWITCH
L	OFF
H	ON

logic diagram (positive logic)



One of Four Switches

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} (see Note 1) . . . . . –0.5 V to 7 V
Input voltage range, V_I (see Note 1) . . . . . –0.5 V to 7 V
Switch I/O voltage range, V_{IO} (see Notes 1 and 2) . . . . . –0.5 V to V_{CC} + 0.5 V
Control-input clamp current, I_{IK} ($V_I < 0$) . . . . . –20 mA
I/O diode current, I_{IOK} ($V_{IO} < 0$ or $V_{IO} > V_{CC}$) . . . . . ±50 mA
On-state switch current, I_T ($V_{IO} = 0$ to V_{CC}) . . . . . ±25 mA
Continuous current through V_{CC} or GND . . . . . ±50 mA
Package thermal impedance, θ_{JA} (see Note 3): D package . . . . . 86°C/W
(see Note 3): DB package . . . . . 96°C/W
(see Note 3): DGV package . . . . . 127°C/W
(see Note 3): N package . . . . . 80°C/W
(see Note 3): NS package . . . . . 76°C/W
(see Note 3): PW package . . . . . 113°C/W
(see Note 4): RGY package . . . . . 47°C/W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The package thermal impedance is calculated in accordance with JESD 51-7.
4. The package thermal impedance is calculated in accordance with JESD 51-5.

recommended operating conditions (see Note 5)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2†	5.5	V
V_{IH}	High-level input voltage, control inputs	V_{CC} = 2 V	1.5		V
		V_{CC} = 2.3 V to 2.7 V	$V_{CC} \times 0.7$		
		V_{CC} = 3 V to 3.6 V	$V_{CC} \times 0.7$		
		V_{CC} = 4.5 V to 5.5 V	$V_{CC} \times 0.7$		
V_{IL}	Low-level input voltage, control inputs	V_{CC} = 2 V		0.5	V
		V_{CC} = 2.3 V to 2.7 V		$V_{CC} \times 0.3$	
		V_{CC} = 3 V to 3.6 V		$V_{CC} \times 0.3$	
		V_{CC} = 4.5 V to 5.5 V		$V_{CC} \times 0.3$	
V_I	Control input voltage		0	5.5	V
V_{IO}	Input/output voltage		0	V_{CC}	V
$\Delta t/\Delta v$	Input transition rise or fall rate	V_{CC} = 2.3 V to 2.7 V		200	ns/V
		V_{CC} = 3 V to 3.6 V		100	
		V_{CC} = 4.5 V to 5.5 V		20	
T_A	Operating free-air temperature		–40	85	°C

† With supply voltages at or near 2 V, the analog switch on-state resistance becomes very nonlinear. Only digital signals should be transmitted at these low supply voltages.

NOTE 5: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	T_A = 25°C			MIN	MAX	UNIT
				MIN	TYP	MAX			
r_{on}	On-state switch resistance	I_T = –1 mA, V_I = V_{CC} or GND, V_C = V_{IH} (see Figure 1)	2.3 V		38	180		225	Ω
			3 V		29	150		190	
			4.5 V		21	75		100	
$r_{on(p)}$	Peak on-state resistance	I_T = –1 mA, V_I = V_{CC} to GND, V_C = V_{IH}	2.3 V		143	500		600	Ω
			3 V		57	180		225	
			4.5 V		31	100		125	
Δr_{on}	Difference in on-state resistance between switches	I_T = –1 mA, V_I = V_{CC} to GND, V_C = V_{IH}	2.3 V		6	30		40	Ω
			3 V		3	20		30	
			4.5 V		2	15		20	
I_I	Control input current	V_I = 5.5 V or GND	0 to 5.5 V			±0.1		±1	μA
$I_{S(off)}$	Off-state switch leakage current	V_I = V_{CC} and V_O = GND, or V_I = GND and V_O = V_{CC}, V_C = V_{IL} (see Figure 2)	5.5 V			±0.1		±1	μA
$I_{S(on)}$	On-state switch leakage current	V_I = V_{CC} or GND, V_C = V_{IH} (see Figure 3)	5.5 V			±0.1		±1	μA
I_{CC}	Supply current	V_I = V_{CC} or GND	5.5 V					20	μA
C_{ic}	Control input capacitance				1.5				pF
C_{io}	Switch input/output capacitance				5.5				pF
C_F	Feed-through capacitance				0.5				pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V ± 0.2 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	T_A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
t_{PLH} t_{PHL}	Propagation delay time	A or B	B or A	C_L = 15 pF, (see Figure 4)		1.2	10		16	ns
t_{PZH} t_{PZL}	Switch turn-on time	C	A or B	C_L = 15 pF, R_L = 1 kΩ (see Figure 5)		3.3	15		20	ns
t_{PLZ} t_{PHZ}	Switch turn-off time	C	A or B	C_L = 15 pF, R_L = 1 kΩ (see Figure 5)		6	15		23	ns
t_{PLH} t_{PHL}	Propagation delay time	A or B	B or A	C_L = 50 pF, (see Figure 4)		2.6	12		18	ns
t_{PZH} t_{PZL}	Switch turn-on time	C	A or B	C_L = 50 pF, R_L = 1 kΩ (see Figure 5)		4.2	25		32	ns
t_{PLZ} t_{PHZ}	Switch turn-off time	C	A or B	C_L = 50 pF, R_L = 1 kΩ (see Figure 5)		9.6	25		32	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	T_A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
t_{PLH} t_{PHL}	Propagation delay time	A or B	B or A	C_L = 15 pF, (see Figure 4)		0.8	6		10	ns
t_{PZH} t_{PZL}	Switch turn-on time	C	A or B	C_L = 15 pF, R_L = 1 kΩ (see Figure 5)		2.3	11		15	ns
t_{PLZ} t_{PHZ}	Switch turn-off time	C	A or B	C_L = 15 pF, R_L = 1 kΩ (see Figure 5)		4.5	11		15	ns
t_{PLH} t_{PHL}	Propagation delay time	A or B	B or A	C_L = 50 pF, (see Figure 4)		1.5	9		12	ns
t_{PZH} t_{PZL}	Switch turn-on time	C	A or B	C_L = 50 pF, R_L = 1 kΩ (see Figure 5)		3	18		22	ns
t_{PLZ} t_{PHZ}	Switch turn-off time	C	A or B	C_L = 50 pF, R_L = 1 kΩ (see Figure 5)		7.2	18		22	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	T_A = 25°C			MIN	MAX	UNIT
					MIN	TYP	MAX			
t_{PLH} t_{PHL}	Propagation delay time	A or B	B or A	C_L = 15 pF, (see Figure 4)		0.3	4		7	ns
t_{PZH} t_{PZL}	Switch turn-on time	C	A or B	C_L = 15 pF, R_L = 1 kΩ (see Figure 5)		1.6	7		10	ns
t_{PLZ} t_{PHZ}	Switch turn-off time	C	A or B	C_L = 15 pF, R_L = 1 kΩ (see Figure 5)		3.2	7		10	ns
t_{PLH} t_{PHL}	Propagation delay time	A or B	B or A	C_L = 50 pF, (see Figure 4)		0.6	6		8	ns
t_{PZH} t_{PZL}	Switch turn-on time	C	A or B	C_L = 50 pF, R_L = 1 kΩ (see Figure 5)		2.1	12		16	ns
t_{PLZ} t_{PHZ}	Switch turn-off time	C	A or B	C_L = 50 pF, R_L = 1 kΩ (see Figure 5)		5.1	12		16	ns

analog switch characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		V_{CC}	T_A = 25°C			UNIT
						MIN	TYP	MAX	
Frequency response (switch on)	A or B	B or A	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) $20\log_{10}(V_O/V_I)$ = –3 dB (see Figure 6)		2.3 V		30		MHz
					3 V		35		
					4.5 V		50		
Crosstalk (between any switches)	A or B	B or A	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (sine wave) (see Figure 7)		2.3 V		–45		dB
					3 V		–45		
					4.5 V		–45		
Crosstalk (control input to signal output)	C	A or B	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (square wave) (see Figure 8)		2.3 V		15		mV
					3 V		20		
					4.5 V		50		
Feed-through attenuation (switch off)	A or B	B or A	C_L = 50 pF, R_L = 600 Ω, f_{in} = 1 MHz (see Figure 9)		2.3 V		–40		dB
					3 V		–40		
					4.5 V		–40		
Sine-wave distortion	A or B	B or A	C_L= 50 pF, R_L = 10 kΩ, f_{in} = 1 kHz (sine wave) (see Figure 10)	V_I = 2 V_{p-p}	2.3 V		0.1		%
				V_I = 2.5 V_{p-p}	3 V		0.1		
				V_I = 4 V_{p-p}	4.5 V		0.1		

operating characteristics, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance	C_L = 50 pF,	f = 10 MHz	4.5	pF

PARAMETER MEASUREMENT INFORMATION

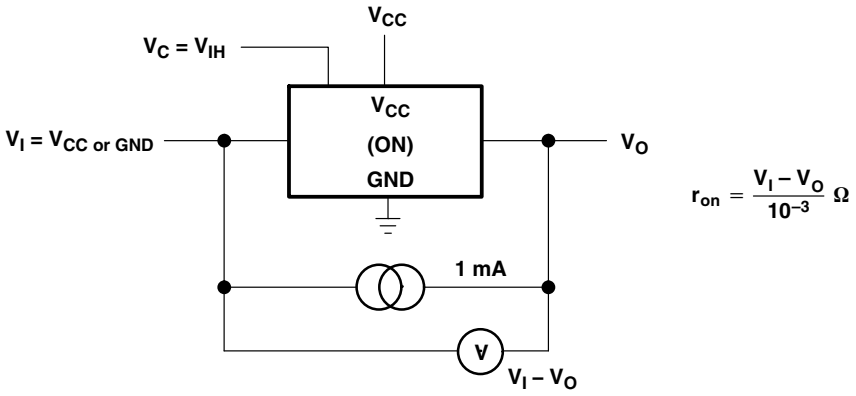


Figure 1. On-State Resistance Test Circuit

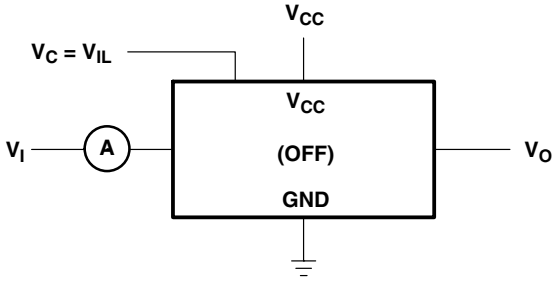


Figure 2. Off-State Switch Leakage-Current Test Circuit

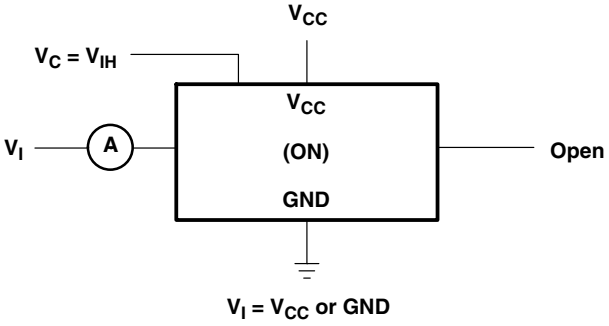


Figure 3. On-State Leakage-Current Test Circuit

PARAMETER MEASUREMENT INFORMATION

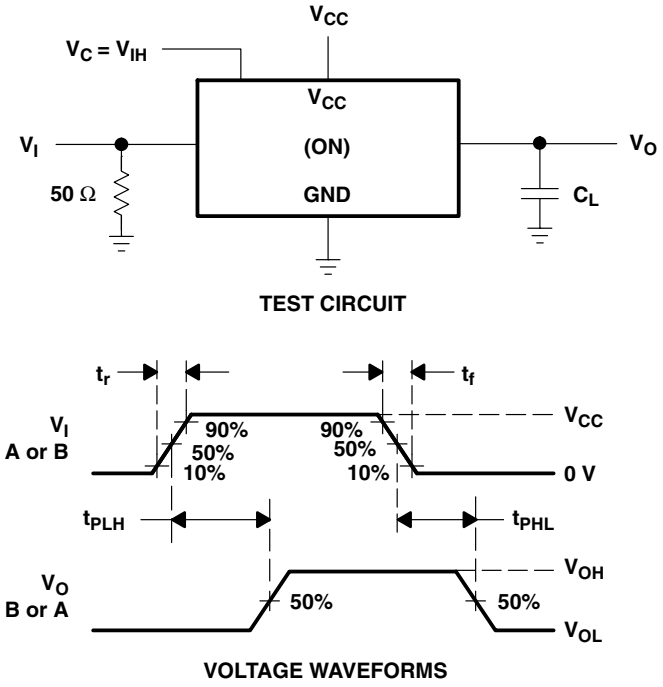
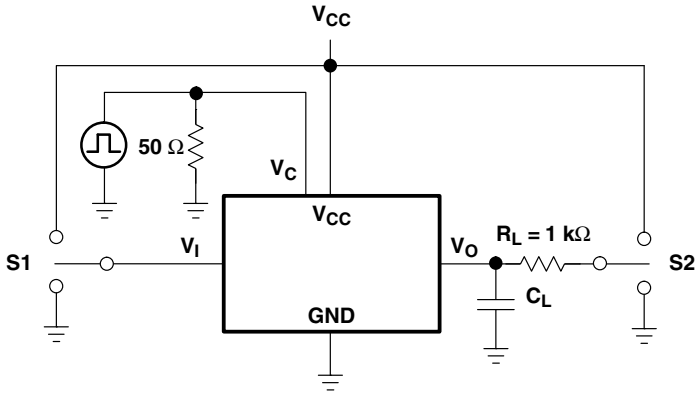


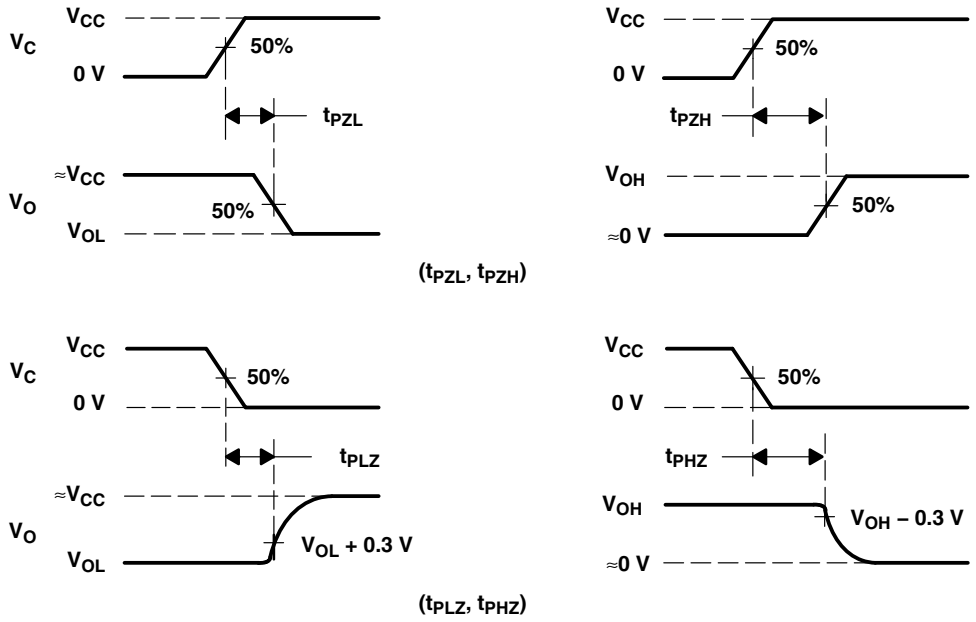
Figure 4. Propagation Delay Time, Signal Input to Signal Output

PARAMETER MEASUREMENT INFORMATION



TEST	S1	S2
t_{PZL}	GND	V_{CC}
t_{PZH}	V_{CC}	GND
t_{PLZ}	GND	V_{CC}
t_{PHZ}	V_{CC}	GND

TEST CIRCUIT



VOLTAGE WAVEFORMS

Figure 5. Switching Time (t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}), Control to Signal Output

PARAMETER MEASUREMENT INFORMATION

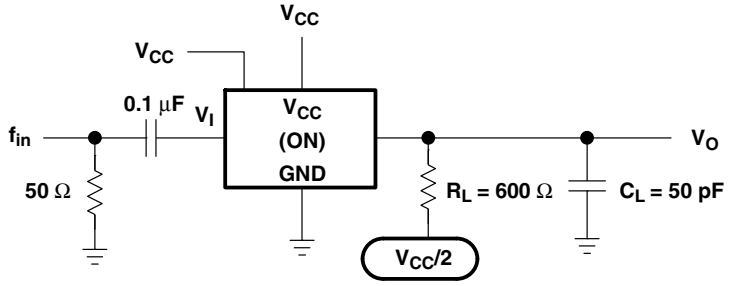


Figure 6. Frequency Response (Switch On)

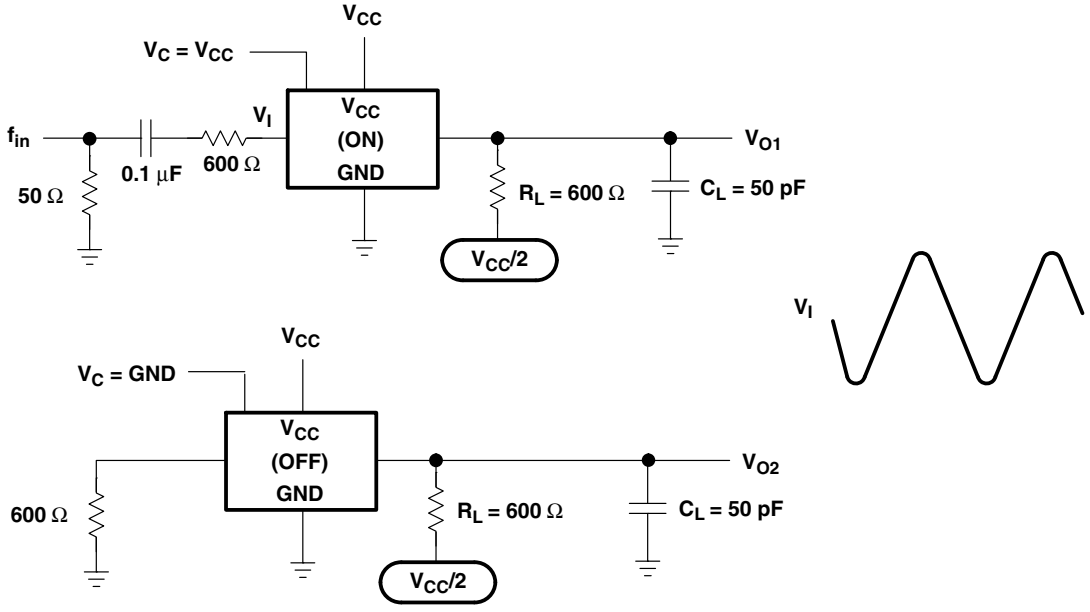


Figure 7. Crosstalk Between Any Two Switches

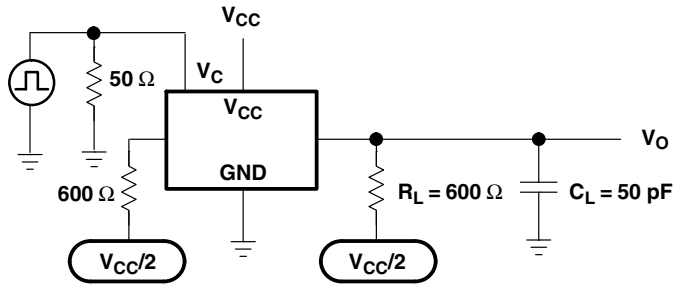


Figure 8. Crosstalk (Control Input – Switch Output)

PARAMETER MEASUREMENT INFORMATION

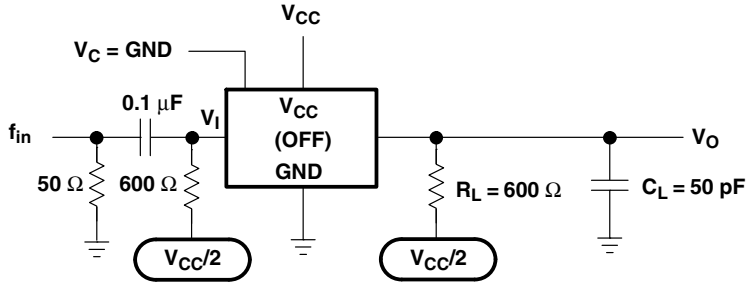


Figure 9. Feed-Through Attenuation (Switch Off)

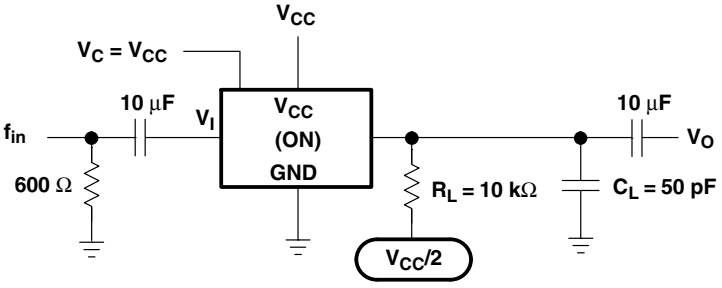


Figure 10. Sine-Wave Distortion

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC4066D	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC4066	
SN74AHC4066DBR	LIFEBUY	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HA4066	
SN74AHC4066DGVR	LIFEBUY	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HA4066	
SN74AHC4066DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC4066	Samples
SN74AHC4066N	LIFEBUY	PDIP	N	14	25	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74AHC4066N	
SN74AHC4066NSR	LIFEBUY	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC4066	
SN74AHC4066PW	LIFEBUY	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HA4066	
SN74AHC4066PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HA4066	Samples
SN74AHC4066RGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HA4066	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

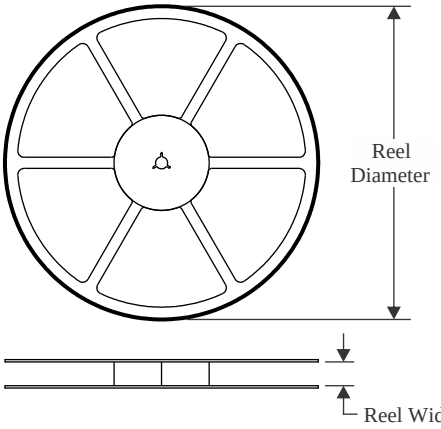
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

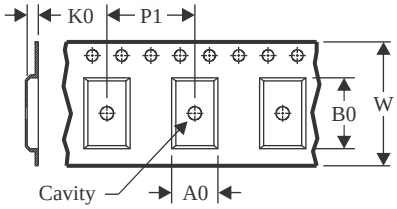
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

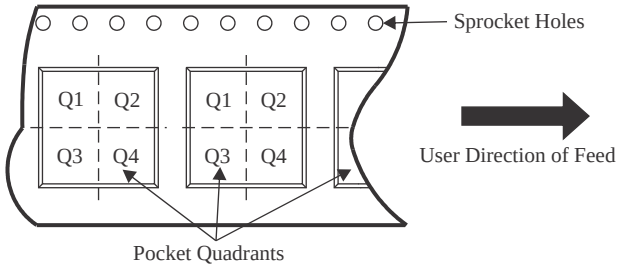


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

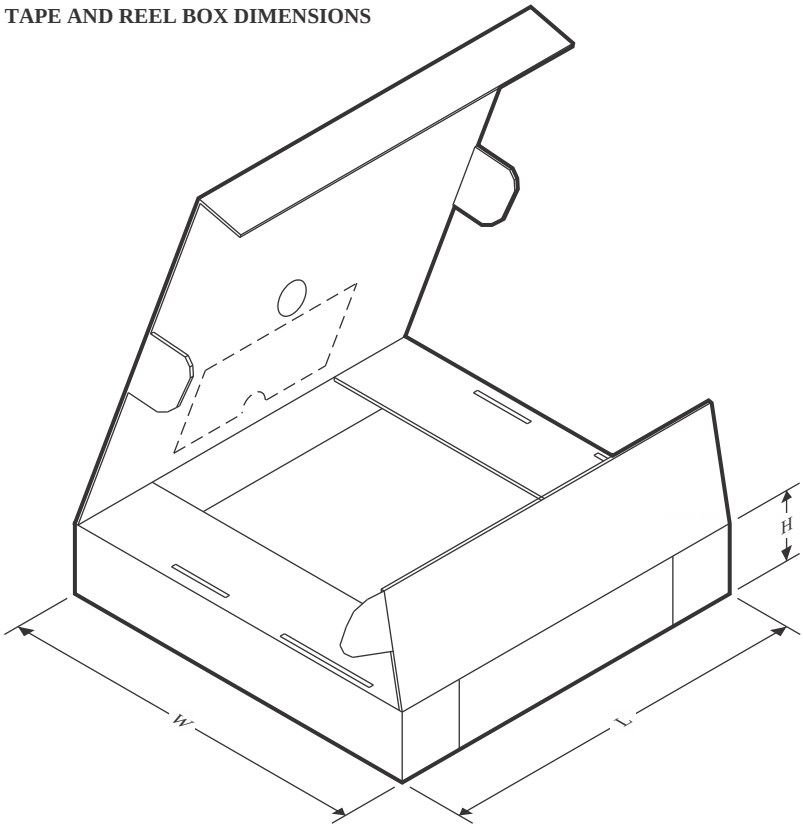
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC4066DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHC4066DGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AHC4066DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC4066NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74AHC4066PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC4066RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

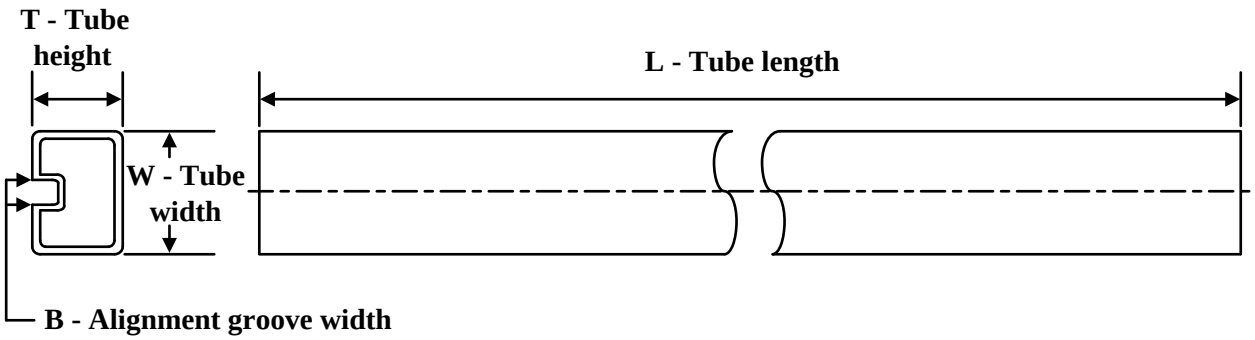
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC4066DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74AHC4066DGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74AHC4066DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74AHC4066NSR	SO	NS	14	2000	356.0	356.0	35.0
SN74AHC4066PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHC4066RGYR	VQFN	RGY	14	3000	367.0	367.0	35.0

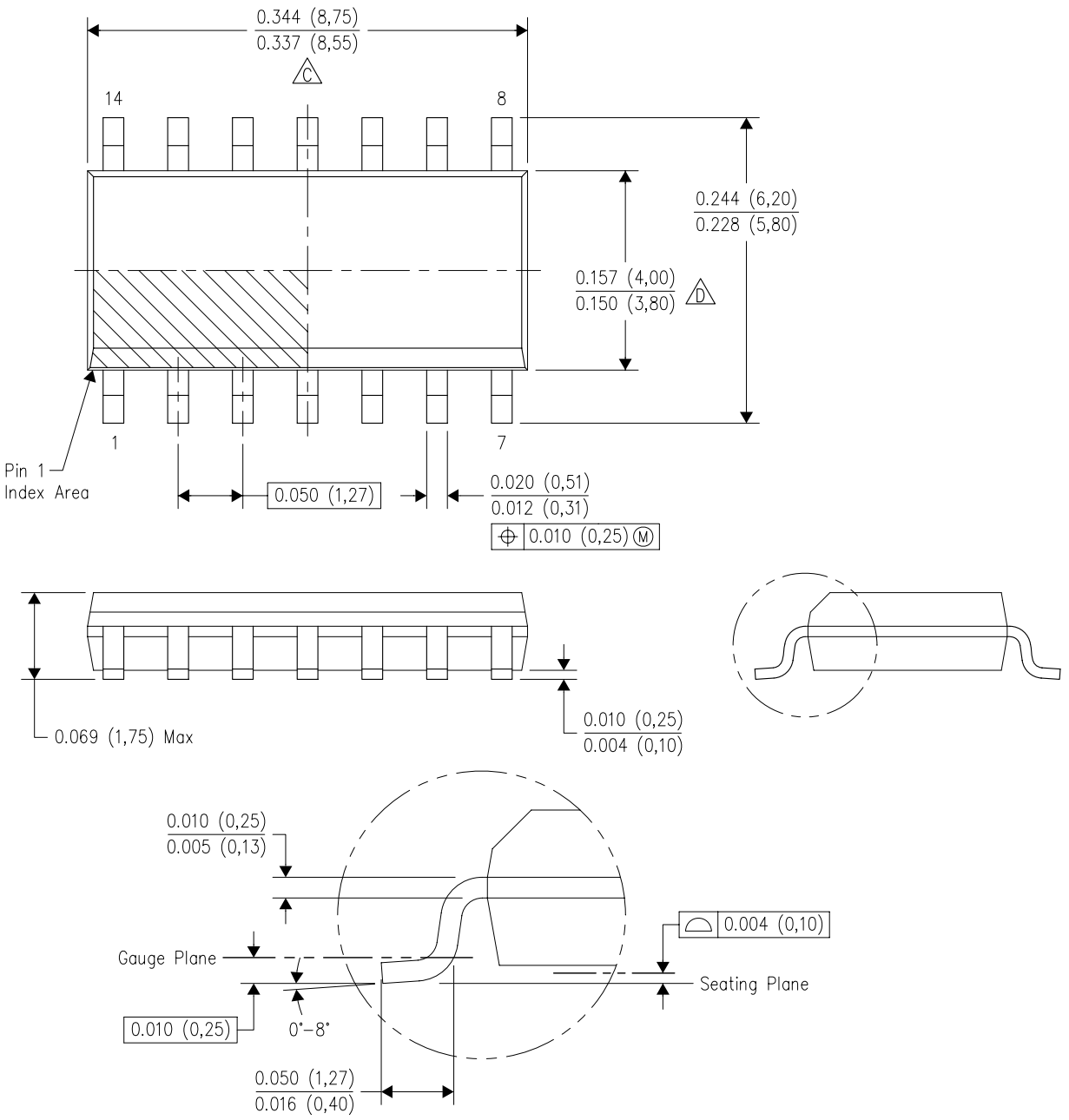
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74AHC4066D	D	SOIC	14	50	506.6	8	3940	4.32
SN74AHC4066N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC4066PW	PW	TSSOP	14	90	530	10.2	3600	3.5

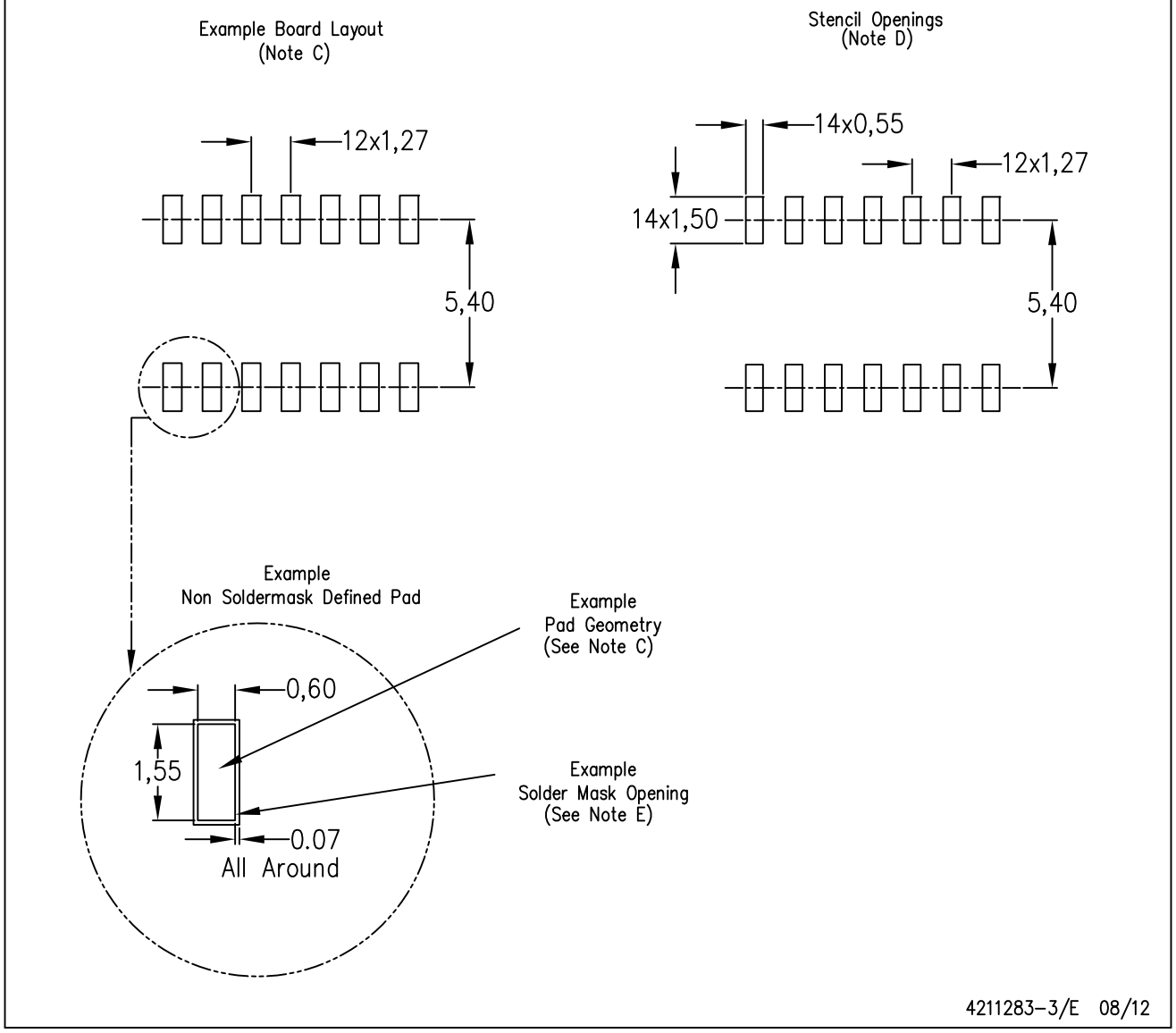
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

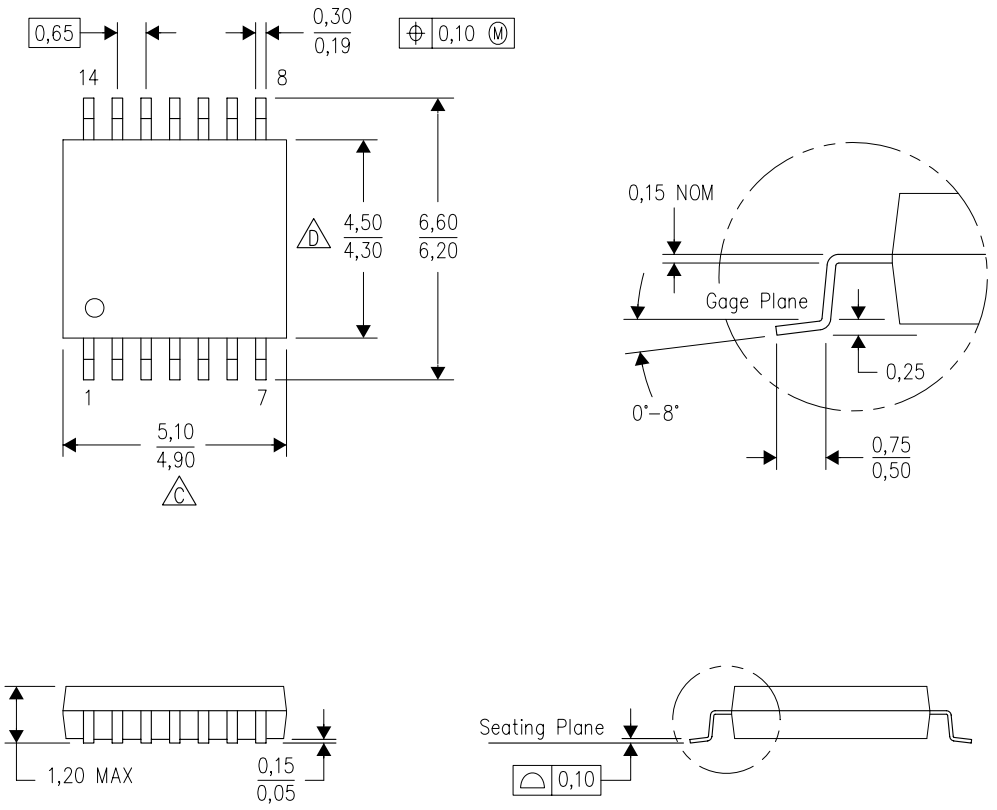
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

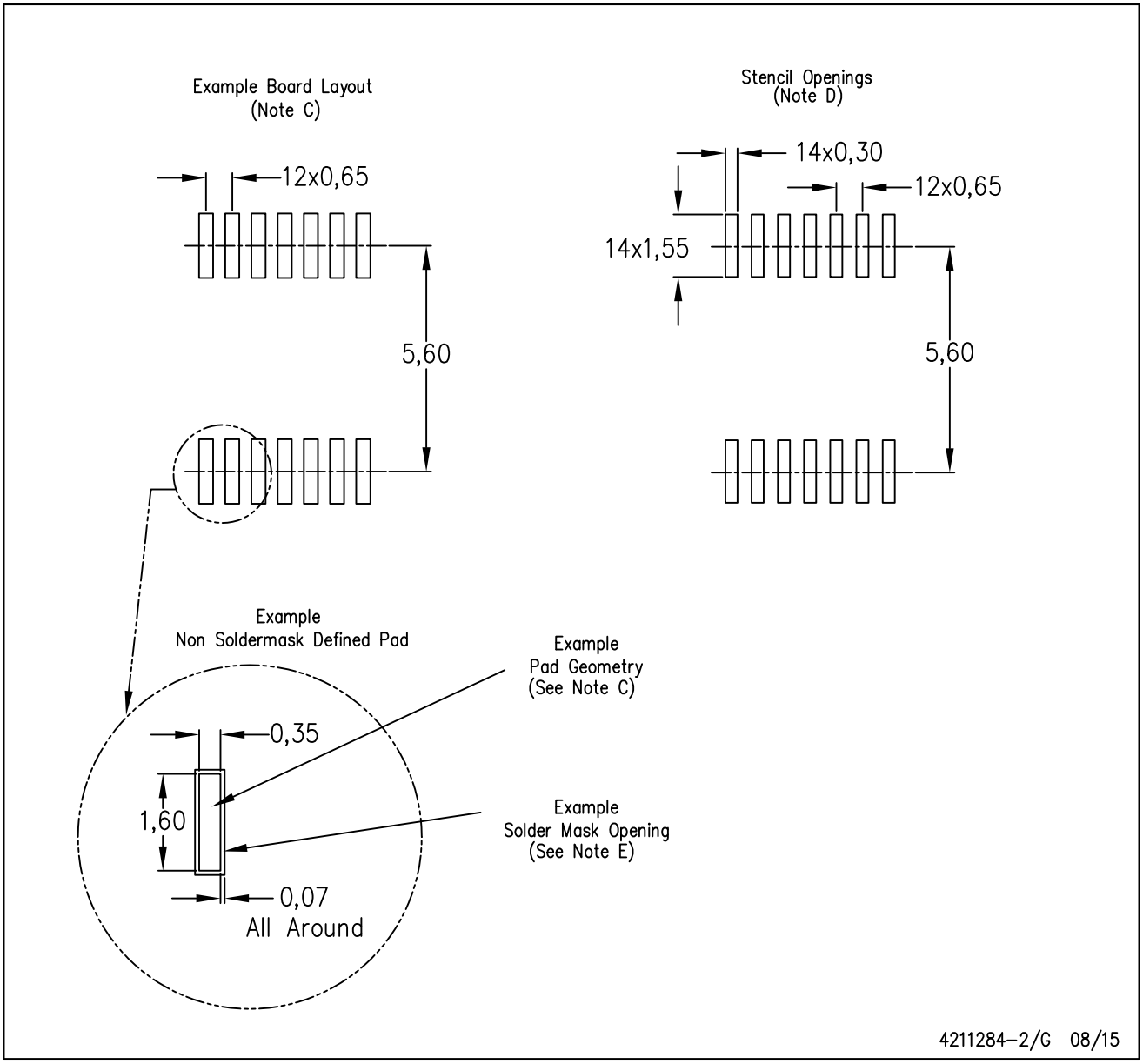
PW (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040064–3/G 02/11

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

PW (R–PDSO–G14) PLASTIC SMALL OUTLINE

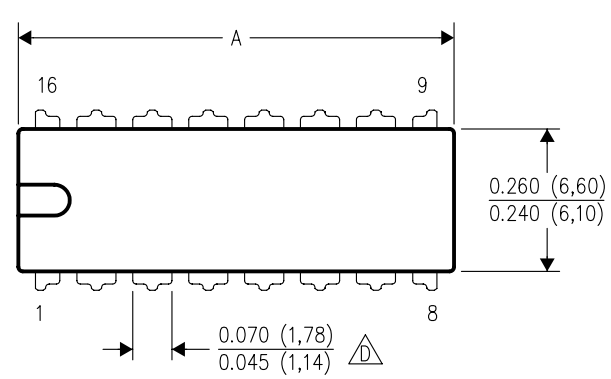


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

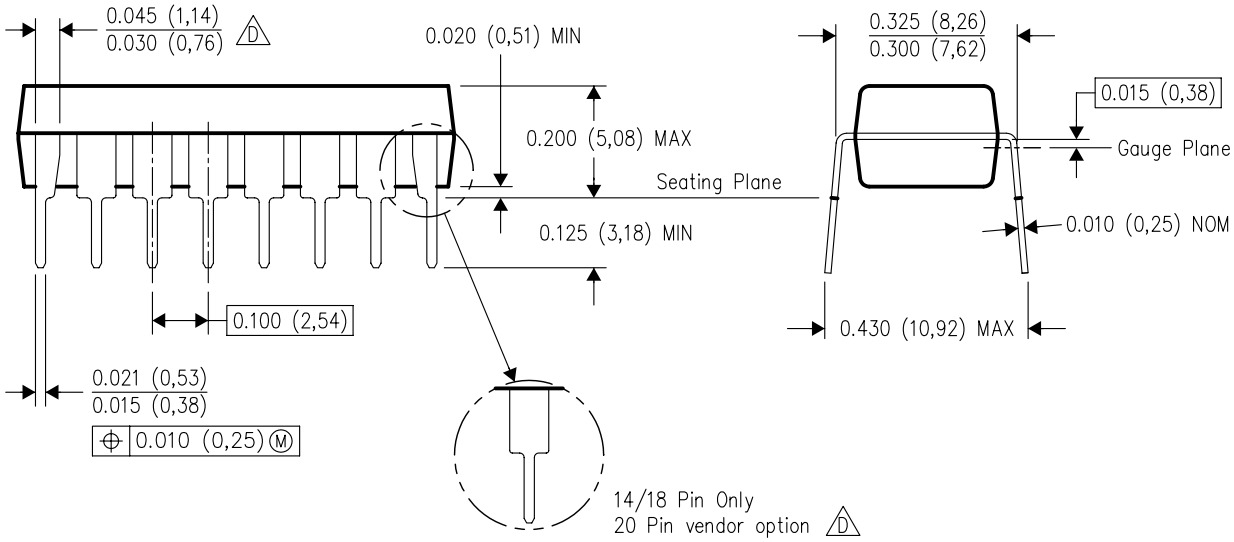
N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION (C)	AA	BB	AC	AD



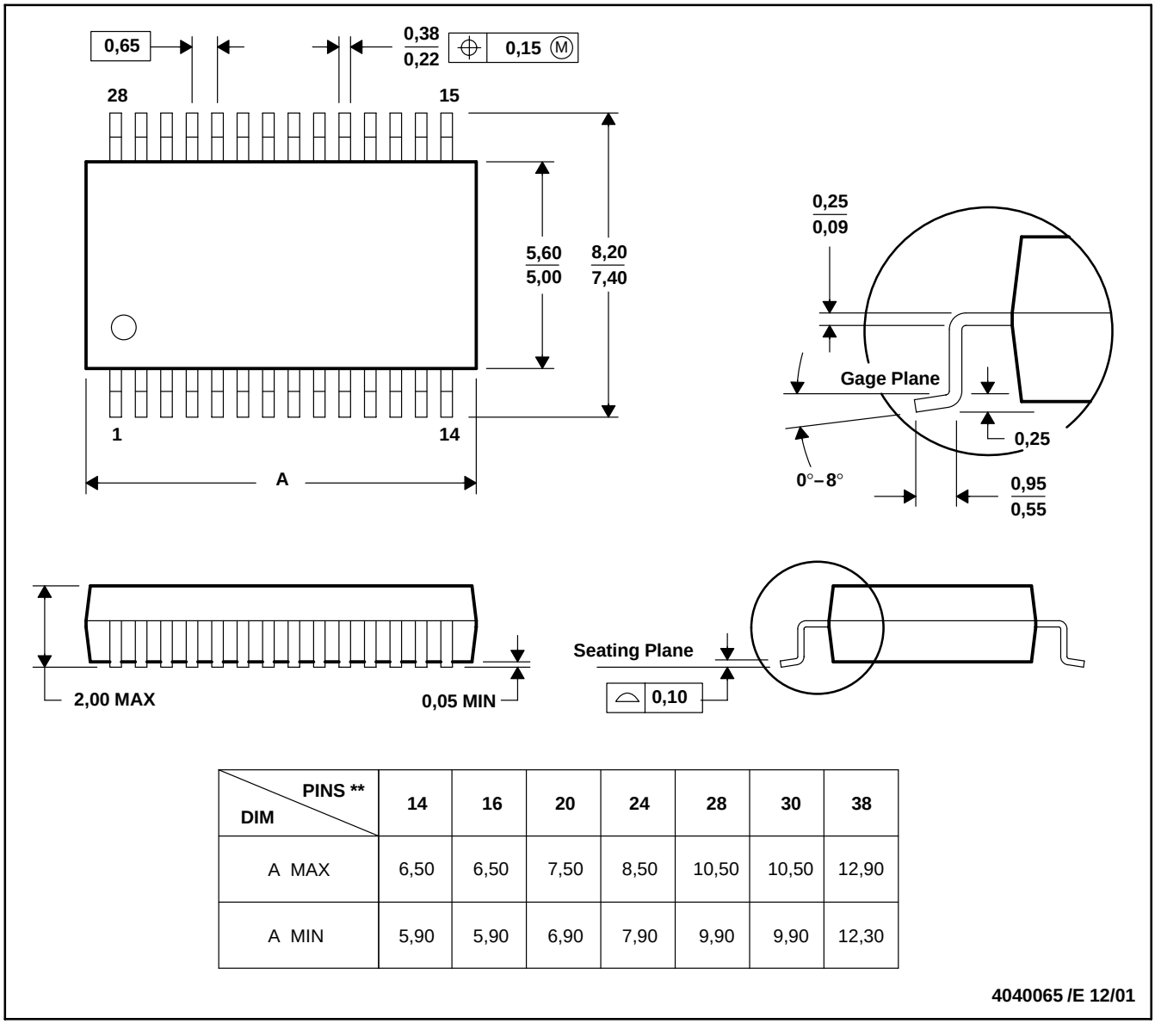
4040049/E 12/2002

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

MSSO002E – JANUARY 1995 – REVISED DECEMBER 2001

DB (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN

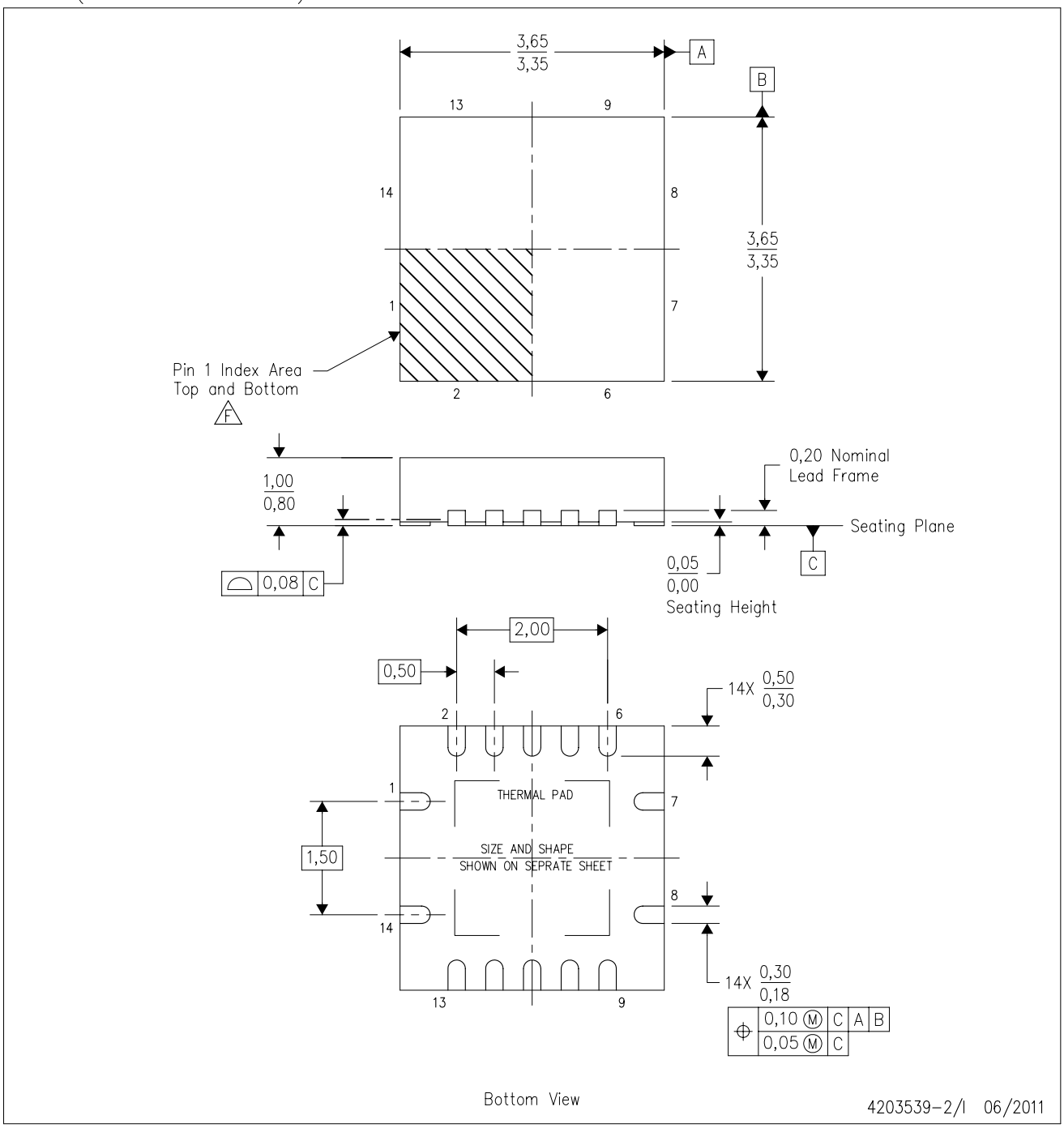


DIM \ PINS **	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-150

RGY (S–PVQFN–N14) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No–Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
G. Package complies to JEDEC MO–241 variation BA.

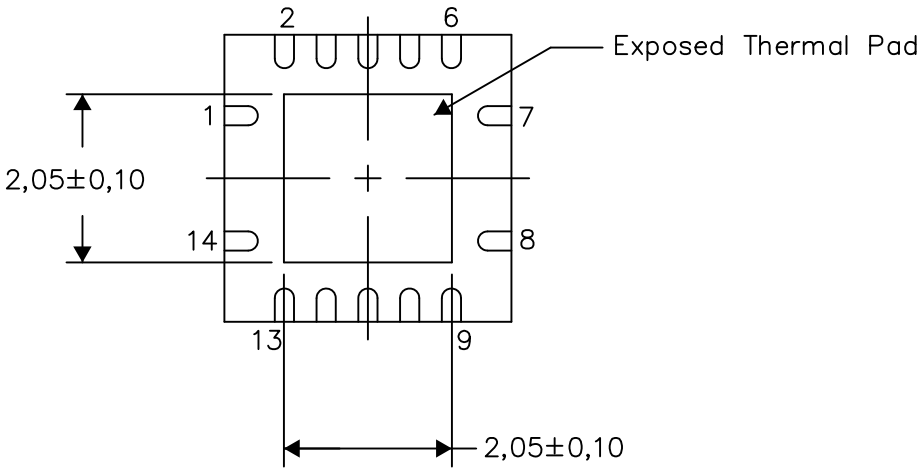
RGY (S–PVQFN–N14) PLASTIC QUAD FLATPACK NO–LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



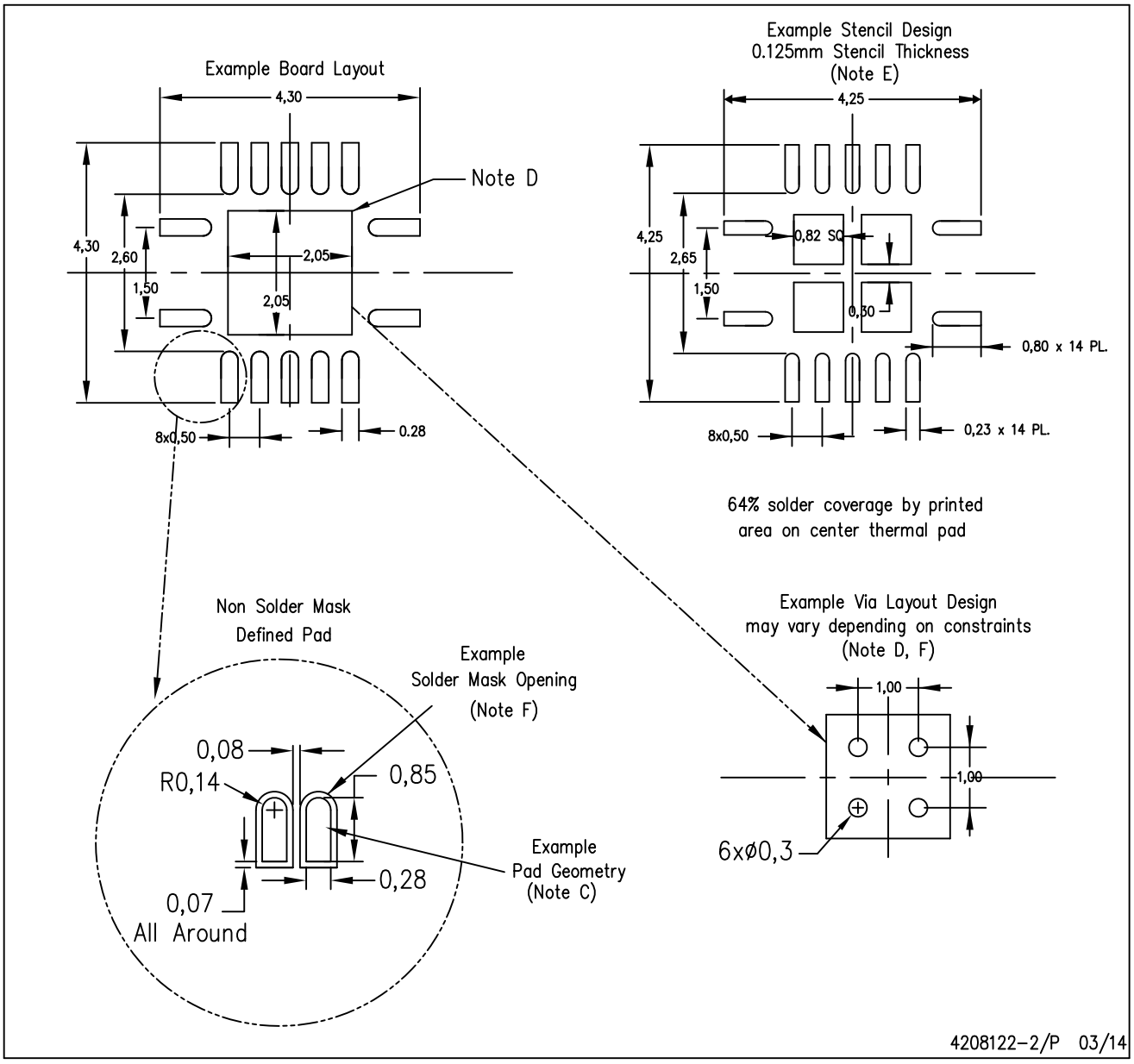
Bottom View

Exposed Thermal Pad Dimensions

4206353–2/P 03/14

NOTE: All linear dimensions are in millimeters

RGY (S–PVQFN–N14) PLASTIC QUAD FLATPACK NO–LEAD

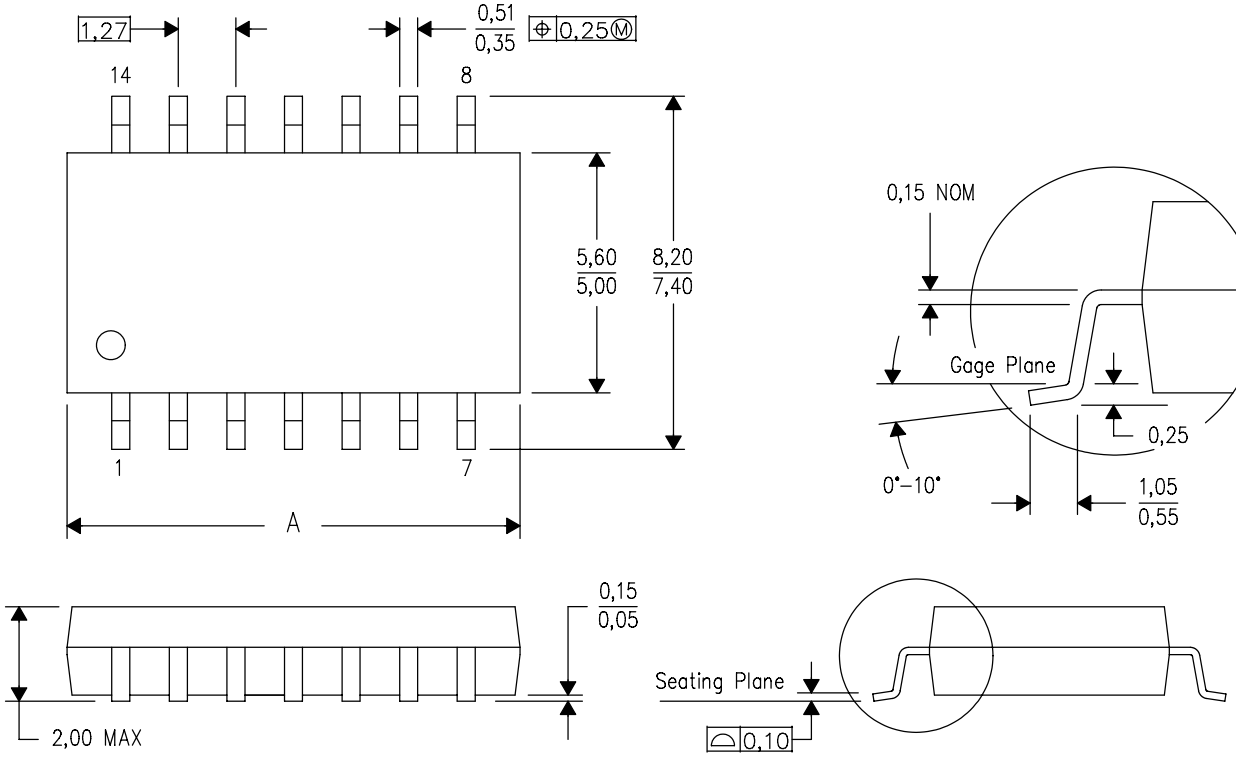


NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat–Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http: //www.ti.com>.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

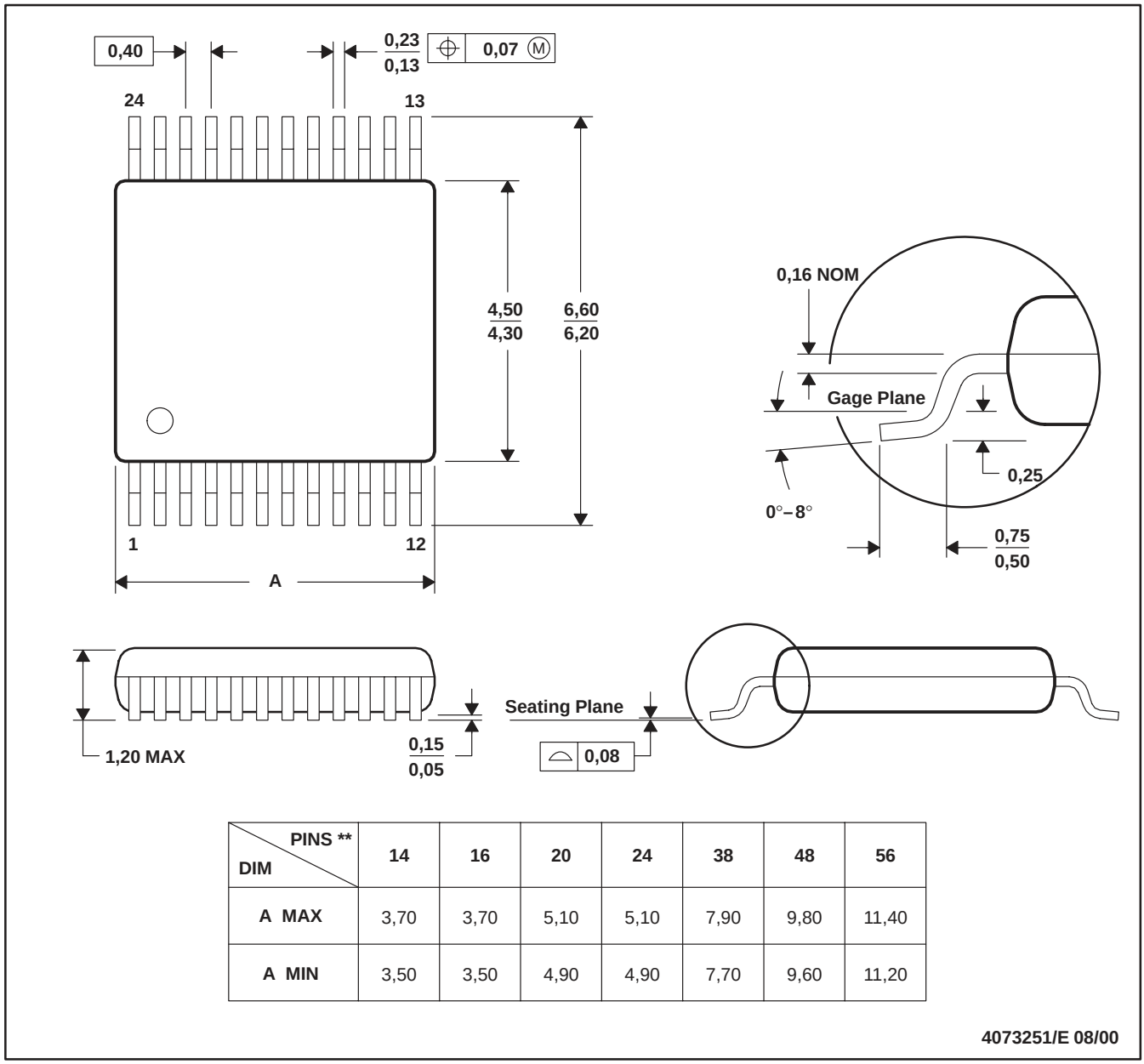
4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

MPDS006C – FEBRUARY 1996 – REVISED AUGUST 2000

DGV (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

24 PINS SHOWN



DIM \ PINS **	14	16	20	24	38	48	56
A MAX	3,70	3,70	5,10	5,10	7,90	9,80	11,40
A MIN	3,50	3,50	4,90	4,90	7,70	9,60	11,20

4073251/E 08/00

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
D. Falls within JEDEC: 24/48 Pins – MO-153
14/16/20/56 Pins – MO-194

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